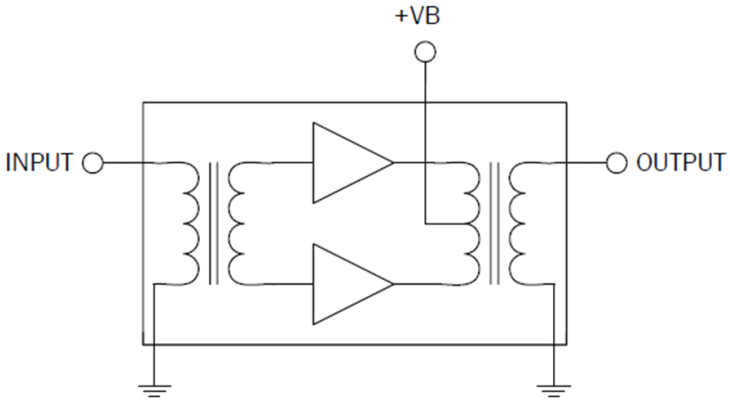
D10040270GTH

GaAs Power Doubler Hybrid
40MHz to 1000MHz



Package: SOT-115J

The D10040270GTH is a Hybrid Power Doubler amplifier module. The part employs GaAs die and is operated from 40MHz to 1000MHz. It provides excellent linearity and superior return loss performance with low noise and optimal reliability.



Features

- High Output Capability
- Excellent Linearity
- Superior Return Loss Performance
- Extremely Low Distortion
- Optimal Reliability
- Low Noise
- Unconditionally Stable Under All Terminations
- 27.0dB Min. Gain at 1GHz
- 440mA Max. at 24VDC

Applications

- 40MHz to 1000MHz CATV Amplifier Systems

Ordering Information

D10040270GTH	Box with 50 pieces

Absolute Maximum Ratings

Parameter	Rating	Unit
RF Input Voltage (single tone)	75	dBmV
DC Supply Over-Voltage (5 minutes)	30	V
Storage Temperature	-40 to +100	°C
Operating Mounting Base Temperature	-30 to +100	°C

Caution! ESD sensitive device.

RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2011/65/EU.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RF Micro Devices Inc. 7628 Thorndike Road, Greensboro, NC 27409-9421
For sales or technical support, contact RFMD at +1.336.678.5570 or customerservice@rfmd.com.

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Nominal Operating Parameters

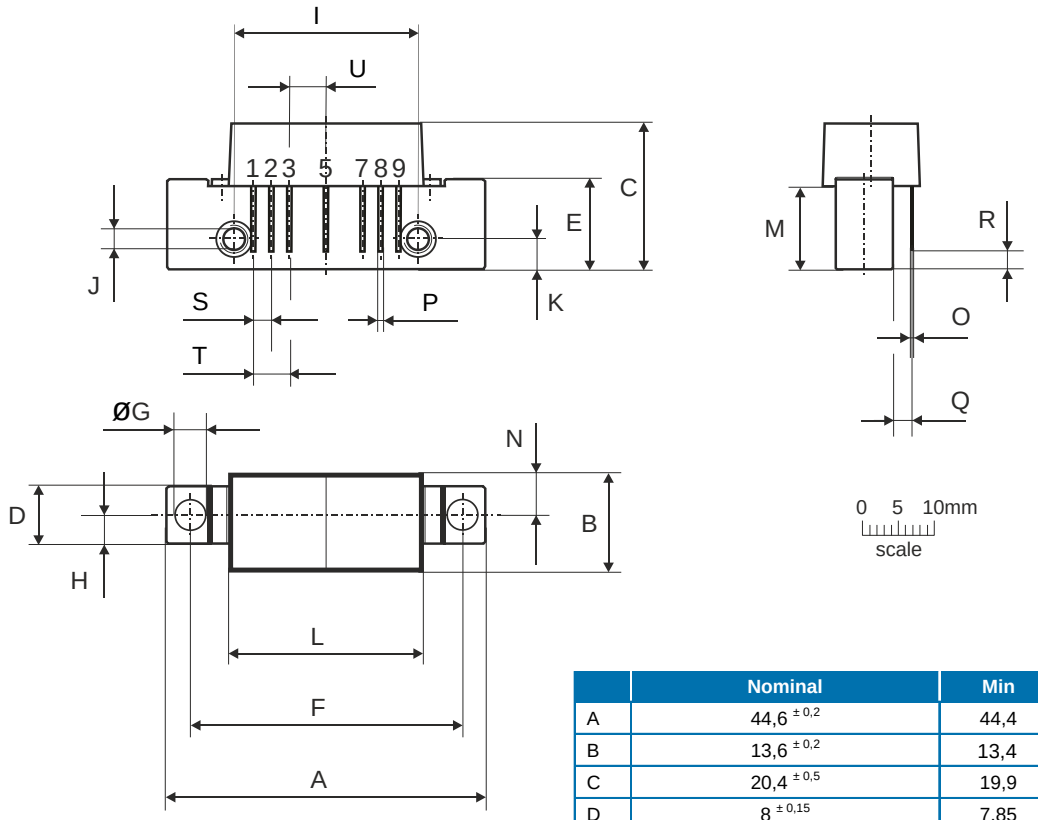
Parameter	Specification			Unit	Condition
	Min	Typ	Max		
General Performance					**V+ = 24V; T_{MB} = 30°C; Z_S = Z_L = 75Ω**
Power Gain	26.0	26.5	27.0	dB	f = 50MHz
	27.0	28.0	28.5	dB	f = 1000MHz
Slope[1]	0.5	1.5	2.0	dB	f = 40MHz to 1000MHz
Flatness of Frequency Response			0.8	dB	f = 40MHz to 1000MHz (Peak to Valley)
Input Return Loss	20.0			dB	f = 40MHz to 320MHz
	19.0			dB	f = 320MHz to 640MHz
	17.0			dB	f = 640MHz to 870MHz
	16.0			dB	f = 870MHz to 1000MHz
Output Return Loss	20.0			dB	f = 40MHz to 320MHz
	19.0			dB	f = 320MHz to 640MHz
	18.0			dB	f = 640MHz to 870MHz
	17.0			dB	f = 870MHz to 1000MHz
Noise Figure		4.5	5.0	dB	f = 50MHz to 1000MHz
Total Current Consumption (DC)		420.0	440.0	mA	
Distortion Data 40MHz to 550MHz					**V+ = 24V; T_{MB} = 30°C; Z_S = Z_L = 75Ω**
CTB		-65	-63	dBc	79ch. 7dB tilt, V_o = 52dBmV at 550MHz[2]
XMOD		-62	-60	dBc	
CSO		-67	-65	dBc	

1. The slope is defined as the difference between the gain at the start frequency and the gain at the stop frequency.

2. 79 channels, NTSC frequency raster: 55.25MHz to 547.25MHz, +45dBmV to +52dBmV tilted output level.
Composite Second Order (CSO) - The CSO parameter (both sum and difference products) is defined by the NCTA.
Composite Triple Beat (CTB) - The CTB parameter is defined by the NCTA.
Cross Modulation (XMOD) - Cross modulation (XMOD) is measured at baseband (selective voltmeter method), referenced to 100% modulation of the carrier being tested.

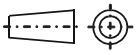
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Package Drawing (Dimensions in millimeters)



Notes:

European Projection



Pinning:

Pin	Name
1	Input
2-3	GND
4	
5	+VB
6	
7-8	GND
9	Output

	Nominal	Min	Max
A	44,6 ± 0,2	44,4	44,8
B	13,6 ± 0,2	13,4	13,8
C	20,4 ± 0,5	19,9	20,9
D	8 ± 0,15	7,85	8,15
E	12,6 ± 0,15	12,45	12,75
F	38,1 ± 0,2	37,9	38,3
G	4 +0,2 / -0,05	3,95	4,2
H	4 ± 0,2	3,8	4,2
I	25,4 ± 0,2	25,2	25,6
J	UNC 6-32	-	-
K	4,2 ± 0,2	4,0	4,4
L	27,2 ± 0,2	27,0	27,4
M	11,6 ± 0,5	11,1	12,1
N	5,8 ± 0,4	5,4	6,2
O	0,25 ± 0,02	0,23	0,27
P	0,45 ± 0,03	0,42	0,48
Q	2,54 ± 0,3	2,24	2,84
R	2,54 ± 0,5	2,04	3,04
S	2,54 ± 0,25	2,29	2,79
T	5,08 ± 0,25	4,83	5,33
U	5,08 ± 0,25	4,83	5,33

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